# 25V PNP SMALL SIGNAL TRANSISTOR IN SOT23

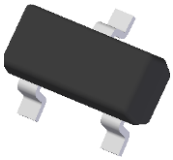
## Features

- Epitaxial Planar Die Construction
- Ideal for Medium Power Amplification and Switching
- Complementary NPN Type: MMBT4124
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

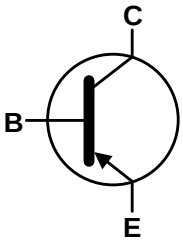
## Mechanical Data

- Case: SOT23
- Case Material: Molded plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish – Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 e3
- Weight: 0.008 grams (Approximate)

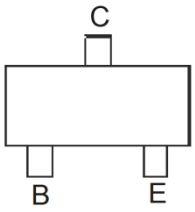
SOT23



Top View




Device Symbol




Top View
Pin-Out

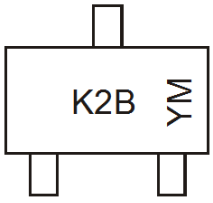
## Ordering Information (Note 4)

| Product | Status | Compliance | Marking | Reel Size (inches) | Tape Width (mm) | Quantity Per Reel |
|---|---|---|---|---|---|---|
| MMBT4126-7-F | Active | AEC-Q101 | K2B | 7 | 8 | 3,000 |

Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## Marking Information

SOT23




K2B = Product Type Marking Code
YM = Date Code Marking
Y or $\overline{Y}$ = Year (ex: D = 2016)
M or $\overline{M}$ = Month (ex: 9 = September)

Date Code Key

| Year | 2016 | 2017 | 2018 | 2019 | 2020 | 2021 | 2022 | 2023 |
|---|---|---|---|---|---|---|---|---|
| Code | D | E | F | G | H | I | J | K |

| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|---|---|---|---|---|---|---|---|---|---|---|---|---|
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | O | N | D |

## Absolute Maximum Ratings (@$T_A$ = +25°C unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---|---|---|---|
| Collector-Base Voltage | $V_{CBO}$ | -25 | V |
| Collector-Emitter Voltage | $V_{CEO}$ | -25 | V |
| Emitter-Base Voltage | $V_{EBO}$ | -4.0 | V |
| Collector Current | $I_C$ | -200 | mA |

## Thermal Characteristics (@$T_A$ = +25°C unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---|---|---|---|
| Power Dissipation (Note 5) | $P_D$ | 200 | mW |
| Thermal Resistance, Junction to Ambient Air (Note 5) | $R_{\theta JA}$ | 625 | °C/W |
| Operating and Storage Temperature Range | $T_J$, $T_{STG}$ | -55 to +150 | °C |

## ESD Ratings (Note 6)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|---|---|---|---|---|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | 400 | V | C |

Notes: 5. For the device mounted on minimum recommended pad layout FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition.
6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

## Thermal Characteristics and Derating Information

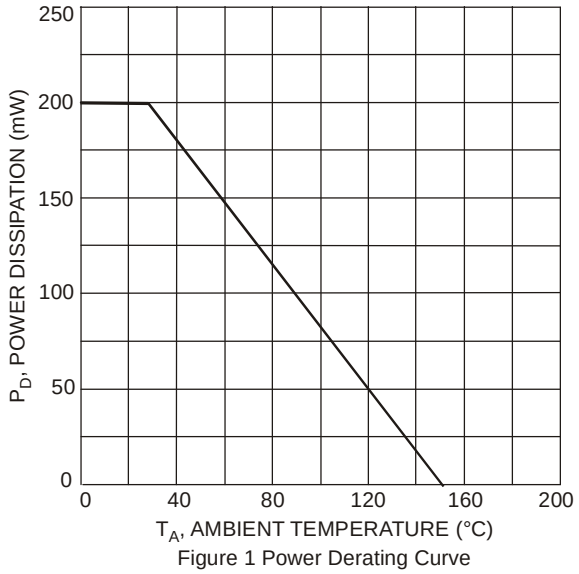


Figure 1 Power Derating Curve

## Electrical Characteristics (@$T_A$ = +25°C unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|---|---|---|---|---|---|---|
| **OFF CHARACTERISTICS** | | | | | | |
| Collector-Base Breakdown Voltage | $BV_{CBO}$ | -25 | — | — | V | $I_C$ = -10μA, $I_B$ = 0 |
| Collector-Emitter Breakdown Voltage (Note 7) | $BV_{CEO}$ | -25 | — | — | V | $I_C$ = -10mA, $I_B$ = 0 |
| Emitter-Base Breakdown Voltage | $BV_{EBO}$ | -4.0 | — | — | V | $I_E$ = -10μA, $I_C$ = 0 |
| Collector Cut-Off Current | $I_{CBO}$ | — | — | -50 | nA | $V_{CB}$ = -20V, $I_E$ = 0 |
| Collector Cut-Off Current | $I_{EBO}$ | — | — | -50 | nA | $V_{EB}$ = -3.0V, $I_C$ = 0 |
| **ON CHARACTERISTICS** (Note 7) | | | | | | |
| DC Current Gain | $h_{FE}$ | 120<br>60 | —<br>— | 360<br>— | — | $I_C$ = -2.0mA, $V_{CE}$ = -1.0V<br>$I_C$ = -50mA, $V_{CE}$ = -1.0V |
| Collector-Emitter Saturation Voltage | $V_{CE(SAT)}$ | — | — | -0.4 | V | $I_C$ = -50mA, $I_B$ = -5.0mA |
| Base-Emitter Saturation Voltage | $V_{BE(SAT)}$ | — | — | -0.95 | V | $I_C$ = -50mA, $I_B$ = 5.0mA |
| **SMALL SIGNAL CHARACTERISTICS** | | | | | | |
| Output Capacitance | $C_{OBO}$ | — | — | 4.5 | pF | $V_{CB}$ = -5.0V, f = 1.0MHz, $I_E$ = 0 |
| Input Capacitance | $C_{IBO}$ | — | — | 10 | pF | $V_{EB}$ = -0.5V, f = 1.0MHz, $I_C$ = 0 |
| Small Signal Current Gain | $h_{FE}$ | 120 | — | 480 | — | $V_{CE}$ = -1.0V, $I_C$ = -2.0mA, f = 1.0kHz |
| Current Gain Bandwidth Product | $f_T$ | 250 | — | — | MHz | $V_{CE}$ = -20V, $I_C$ = -10mA, f = 100MHz |
| Noise Figure | NF | — | — | 4.0 | dB | $V_{CE}$ = -5.0V, $I_C$ = -100μA, $R_S$ = 1.0kΩ, f = 1.0kHz |

Note: 7. Short duration pulse test used to minimize self-heating effect.

## Typical Electrical Characteristics (@$T_A$ = +25°C, unless otherwise specified.)

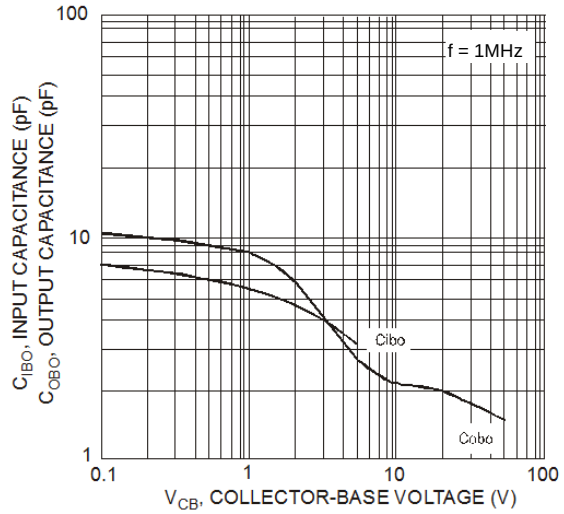



Fig. 2, Input and Output Capacitance vs. Collector-Base Voltage

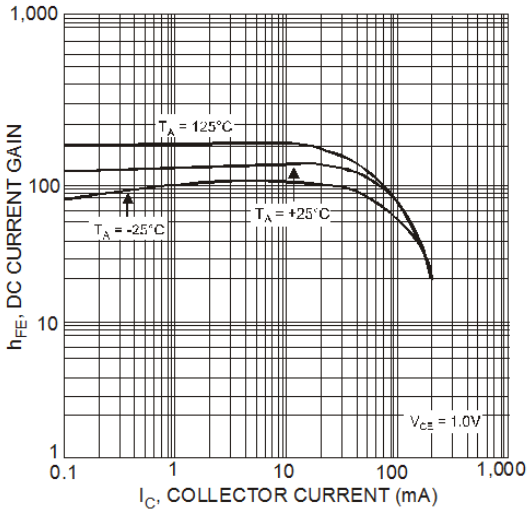



Fig. 3, Typical DC Current Gain vs. Collector Current

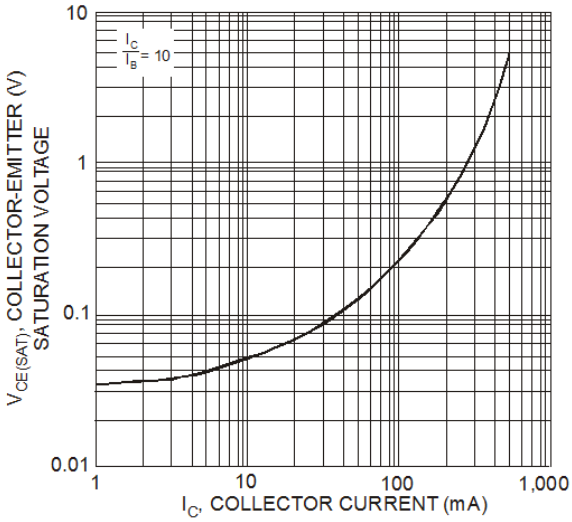



Fig. 4, Typical Collector-Emitter Saturation Voltage vs. Collector Current

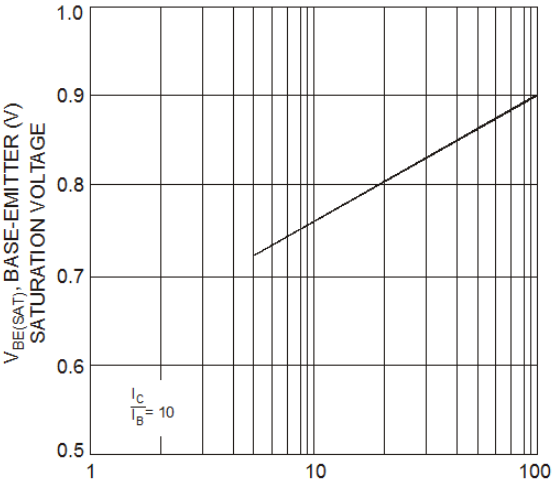
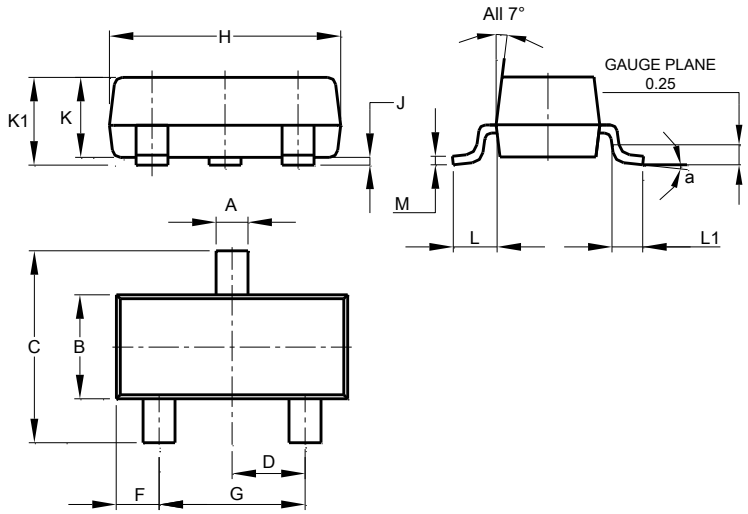



Fig. 5, Typical Base-Emitter Saturation Voltage vs. Collector Current

## Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

**SOT23**

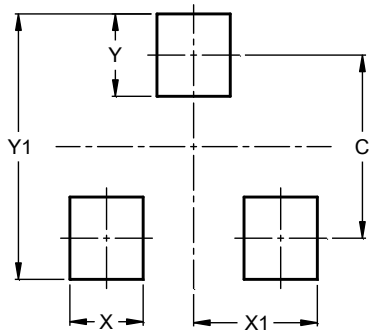



| SOT23 | | | |
|---|---|---|---|
| **Dim** | **Min** | **Max** | **Typ** |
| **A** | 0.37 | 0.51 | 0.40 |
| **B** | 1.20 | 1.40 | 1.30 |
| **C** | 2.30 | 2.50 | 2.40 |
| **D** | 0.89 | 1.03 | 0.915 |
| **F** | 0.45 | 0.60 | 0.535 |
| **G** | 1.78 | 2.05 | 1.83 |
| **H** | 2.80 | 3.00 | 2.90 |
| **J** | 0.013 | 0.10 | 0.05 |
| **K** | 0.890 | 1.00 | 0.975 |
| **K1** | 0.903 | 1.10 | 1.025 |
| **L** | 0.45 | 0.61 | 0.55 |
| **L1** | 0.25 | 0.55 | 0.40 |
| **M** | 0.085 | 0.150 | 0.110 |
| **a** | 0° | 8° | -- |
| **All Dimensions in mm** | | | |

## Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

**SOT23**




| Dimensions | Value (in mm) |
|---|---|
| **C** | 2.0 |
| **X** | 0.8 |
| **X1** | 1.35 |
| **Y** | 0.9 |
| **Y1** | 2.9 |

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